- **EPIC** ™ (Enhanced-Performance Implanted **CMOS) Submicron Process**
- **Package Options Include Plastic** Small-Outline (D), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic (N) and Ceramic (J) DIPS

description

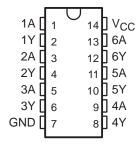
The 'AC14 devices contain six independent inverters. The devices perform the Boolean function Y = A.

The SN54AC14 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AC14 is characterized for operation from -40°C to 85°C.

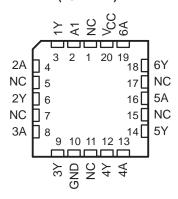
FUNCTION TABLE (each inverter)

INPUT A	OUTPUT Y
Н	L
L	Н

SN54AC14 ... J OR W PACKAGE SN74AC14 ... D, DB, N, OR PW PACKAGE (TOP VIEW)

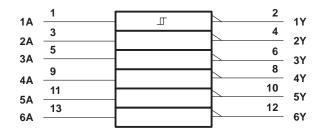


SN54AC14 ... FK PACKAGE (TOP VIEW)



NC - No internal connection

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, DB, J, N, PW, or W packages.

logic diagram, each inverter (positive logic)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		– 0.5 V to 7 V
Input voltage range, V _I (see Note 1)		$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, VO (see Note 1)		$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)		± 20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CO}	C)	± 20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	-	± 50 mA
Continuous current through V _{CC} or GND		± 200 mA
Package thermal impedance, θ _{JA} (see Note 2)	: D package	127°C/W
	DB package	158°C/W
	N package	78°C/W
	PW package	170°C/W
Storage temperature range, T _{stq}		– 65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero

recommended operating conditions (see Note 3)

			SN54	SN54AC14		SN74AC14	
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		2	6	2	6	V
٧ _I	Input voltage		0	VCC	0	VCC	V
۷o	Output voltage		0	VCC	0	VCC	V
IOH High-level output current	High-level output current	V _{CC} = 3 V		-12		-12	
		V _{CC} = 4.5 V		-24		-24	mA
	V _{CC} = 5.5 V		-24		-24		
		V _{CC} = 3 V		12		12	
lOL	Low-level output current	V _{CC} = 4.5 V		24		24	mA
	V _{CC} = 5.5 V			24		24	
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	Т	A = 25°C	;	SN54	AC14	SN74	AC14	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
V _{T+} Positive-going		3 V	0.8	1.8	2.2	0.8	2.2	0.8	2.2	
		4.5 V	1.5	2.6	3.2	1.5	3.2	1.5	3.2	V
threshold		5.5 V	1.6	3.2	3.9	1.6	3.9	1.6	3.9	
V _T _		3 V	0.5	0.8	1	0.5	1	0.5	1	
Negative-going		4.5 V	0.9	1.4	1.8	0.9	1.8	0.9	1.8	V
threshold		5.5 V	1.1	1.8	2.3	1.1	2.3	1.1	2.3	
ΔVΤ		3 V	0.3	1	1.2	0.3	1.2	0.3	1.2	
Hysteresis		4.5 V	0.4	1.2	1.4	0.4	1.4	0.4	1.4	V
$(V_{T+} - V_{T-})$		5.5 V	0.5	1.4	1.6	0.5	1.6	0.5	1.6	
		3 V	2.9			2.9		2.9		
	I _{OH} = - 50 μA	4.5 V	4.4			4.4		4.4		V
		5.5 V	5.4			5.4		5.4		
.,	I _{OH} = - 12 mA	3 V	2.56			2.4		2.48		
VOH	I _{OH} = - 24 mA	4.5 V	3.86			3.7		3.8		
		5.5 V	4.86			4.7		4.8		
	I _{OH} = - 50 mA [†]	5.5 V				3.85				
	I _{OH} = - 75 mA [†]	5.5 V						3.85		
		3 V		0.002	0.1		0.1		0.1	
	I _{OL} = 50 μA	4.5 V		0.001	0.1		0.1		0.1	
		5.5 V		0.001	0.1		0.1		0.1	1
.,	I _{OL} = 12 mA	3 V			0.36		0.5		0.44	.,,
VOL		4.5 V			0.36		0.5		0.44	V
	I _{OL} = 24 mA	5.5 V			0.36		0.5		0.44	1
	I _{OL} = 50 mA [†]	5.5 V					1.65			
	I _{OL} = 75 mA [†]	5.5 V		•					1.65	
l _l	V _I = V _{CC} or GND	5.5 V			±0.1		±1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		40		20	μΑ
Ci	VI = V _{CC} or GND	5 V		4.5						pF

 $^{^{\}dagger}$ Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V $\,\pm\,$ 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Т,	4 = 25°C	;	SN54	AC14	SN74/	AC14	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	Λ.	V	1.5	6	13.5	1	16	1.5	15	20
t _{PHL}	^	I	1.5	6	11.5	1	14	1.5	13	ns



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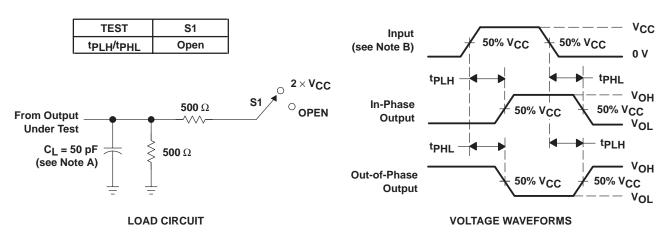
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	T,	4 = 25°C	;	SN54/	AC14	SN74/	AC14	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}		V	1.5	5	10	1.5	12	1.5	11	20
^t PHL	A	Υ	1.5	5	8.5	1.5	10	1.5	9.5	ns

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	$C_L = 50 \text{ pF}, f = 1 \text{ MHz}$	25	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50~\Omega$, $t_f \leq 2.5$ ns, $t_f \leq 2.5$ ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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